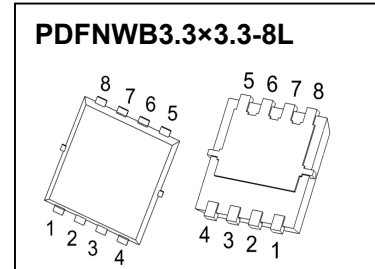




**PDFNWB3.3×3.3-8L Plastic-Encapsulate MOSFETS**

**CJAB25N04A N-Channel Power MOSFET**

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
40V	6.5mΩ@10V	25A
	8.4mΩ@4.5V	



**DESCRIPTION**

The CJAB25N04A uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

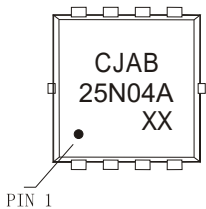
**FEATURES**

- High Power and current handing capability
- Load switch
- High density cell design for ultra low  $R_{DS(ON)}$
- Lead free product is acquired
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

**APPLICATIONS**

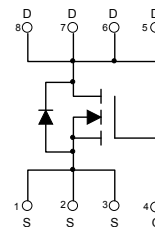
- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply
- Power management

**MARKING**



CJAB25N04A = Part No.  
 Solid dot = Pin1 indicator.  
 XX = Code.

**EQUIVALENT CIRCUIT**



**ABSOLUTE MAXIMUM RATINGS ( $T_J=25^{\circ}C$  unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	40	V
Gate-Source Voltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D^{①}$	25	A
Pulsed Drain Current	$I_{DM}^{①②}$	100	A
Single Pulsed Avalanche Energy	$E_{AS}^{③}$	137	mJ
Power Dissipation	$P_D^{①}$	50	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{⑤}$	83.3	°CW
Thermal Resistance from Junction to Case	$R_{\theta JC}^{①}$	2.5	°CW
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	°C

# MOSFET ELECTRICAL CHARACTERISTICS

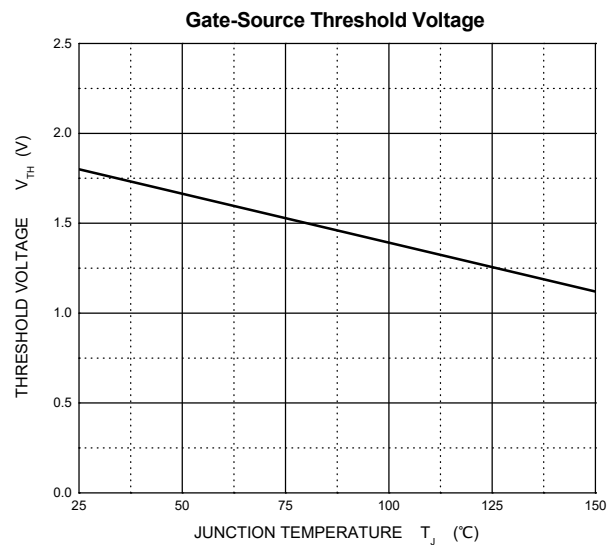
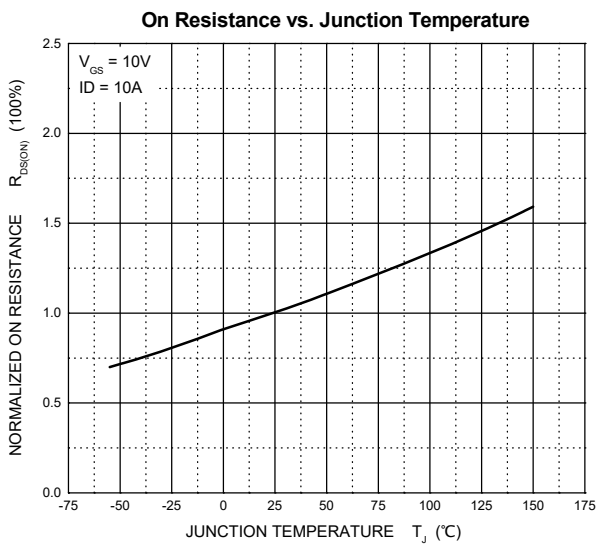
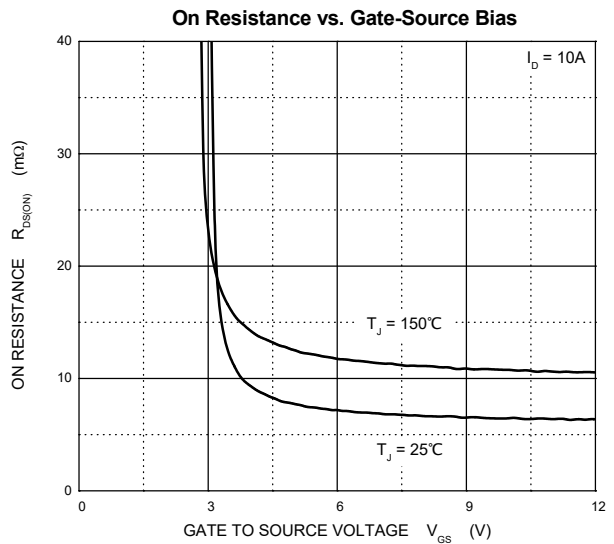
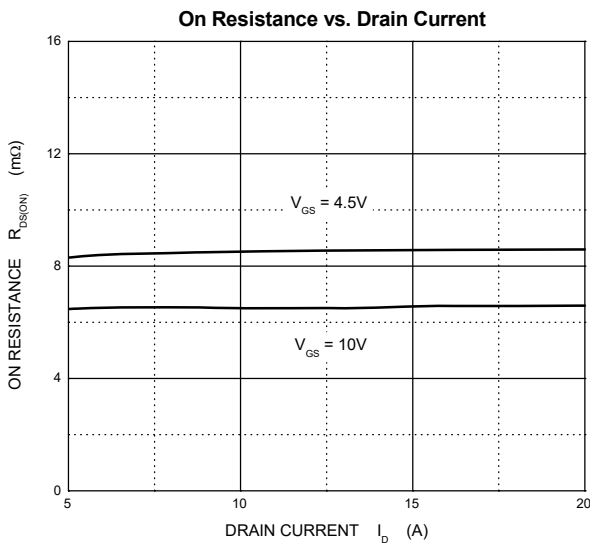
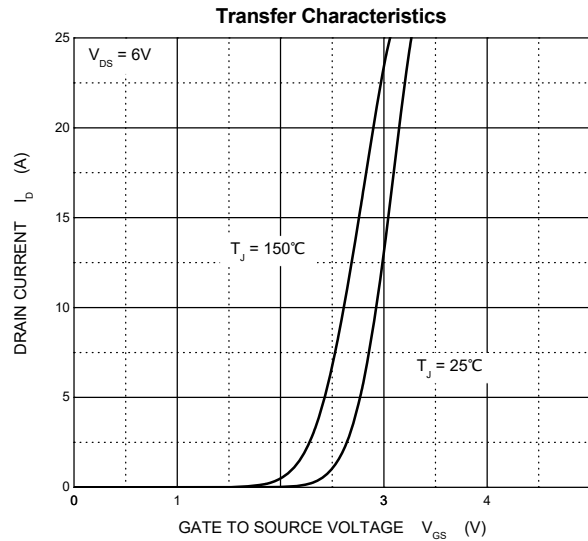
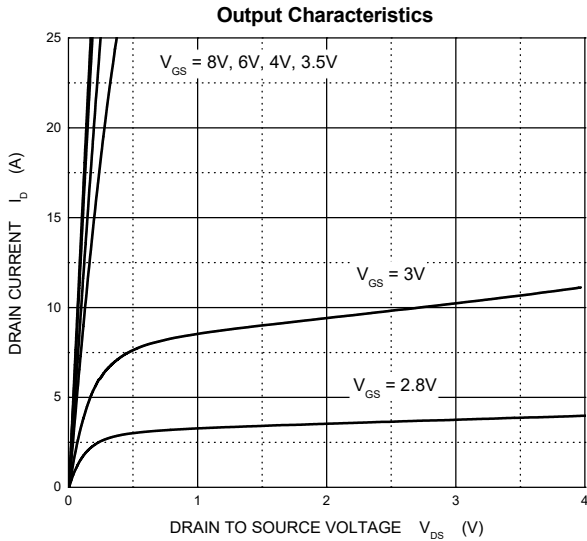
$T_J=25^{\circ}\text{C}$  unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit	
<b>Off characteristics</b>							
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	40	-	-	V	
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 40V, V_{GS} = 0V$	$T_J = 25^{\circ}\text{C}$	-	-	1.0	$\mu A$
			$T_J = 125^{\circ}\text{C}$	-	-	100	
Gate-body leakage current	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	$\pm 100$	nA	
<b>On characteristics</b> <sup>④</sup>							
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.8	2.5	V	
Static drain-source on-state resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 10A$		6.6	8.5	m $\Omega$	
		$V_{GS} = 4.5V, I_D = 10A$		8.5	12	m $\Omega$	
<b>Dynamic characteristics</b>							
Input capacitance	$C_{iss}$	$V_{DS} = 20V, V_{GS} = 0V, f = 1\text{MHz}$	-	2893	-	$\mu F$	
Output capacitance	$C_{oss}$		-	189	-		
Reverse transfer capacitance	$C_{rss}$		-	154	-		
Gate resistance	$R_g$	$f = 1\text{MHz}$	-	3.0	-	$\Omega$	
<b>Switching characteristics</b>							
Total gate charge	$Q_g$	$V_{GS} = 4.5V, V_{DS} = 20V, I_D = 10A$	-	24	-	nC	
Total gate charge	$Q_g$	$V_{GS} = 10V, V_{DS} = 20V, I_D = 10A$	-	51	-		
Gate-source charge	$Q_{gs}$		-	7.3	-		
Gate-drain charge	$Q_{gd}$		-	8.2	-		
Turn-on delay time	$t_{d(on)}$	$V_{DS} = 20V, V_{GS} = 10V, R_L = 2.7\Omega, R_g = 10\Omega$	-	40	-	ns	
Turn-on rise time	$t_r$		-	41	-		
Turn-off delay time	$t_{d(off)}$		-	402	-		
Turn-off fall time	$t_f$		-	116	-		
<b>Drain-Source Diode Characteristics</b>							
Drain-source diode forward voltage	$V_{SD}$ <sup>④</sup>	$V_{GS} = 0V, I_S = 10A$	-	-	1.2	V	
Continuous drain-source diode forward current	$I_S$ <sup>①</sup>		-	-	25	A	
Pulsed drain-source diode forward current	$I_{SM}$ <sup>①②</sup>		-	-	100	A	
Reverse recovery time	$t_{rr}$	$di_S/dt = 100A/\mu s, I_S = 13A, V_{DD} = 30V$	-	23	-	ns	
Reverse recovery charge	$Q_{rr}$		-	13	-	nC	

Notes:

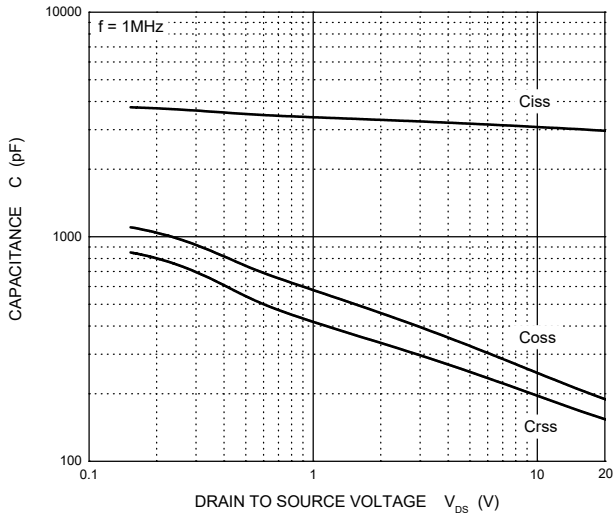
- $T_C = 25^{\circ}\text{C}$ .
- Limited only by maximum temperature allowed.
- $V_{DD} = 20V, V_{GS} = 10V, L = 0.5\text{mH}, R_g = 25\Omega$  Starting  $T_J = 25^{\circ}\text{C}$ .
- Pulse Test : Pulse Width  $\leq 380\mu s$ , duty cycle  $\leq 2\%$ .
- Device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. single-sided Copper, in a still air environment with  $T_A = 25^{\circ}\text{C}$ .

# Typical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

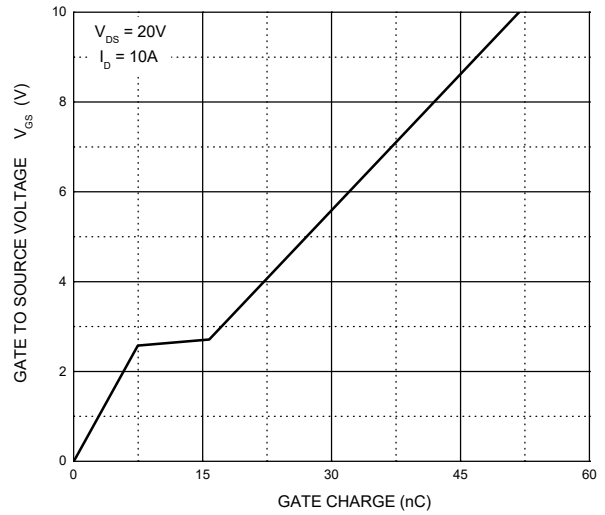


# Typical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

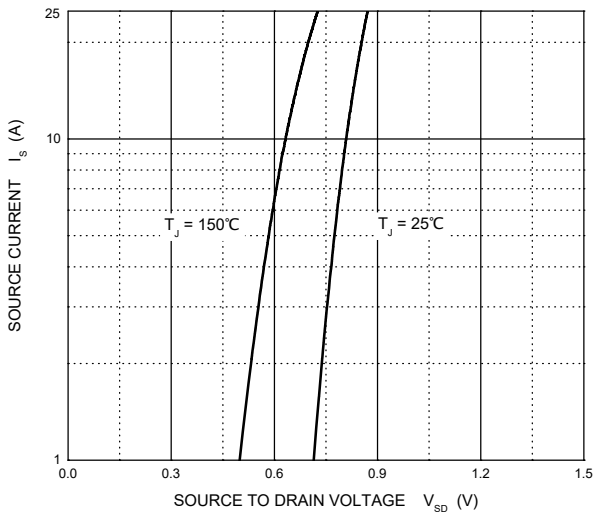
Typical Capacitances



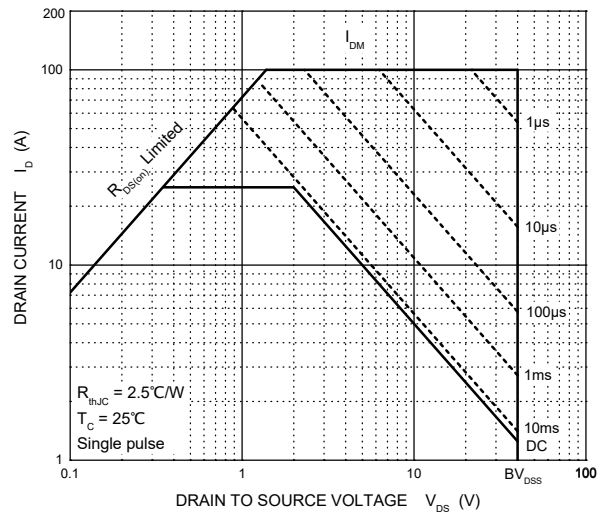
Gate Charge



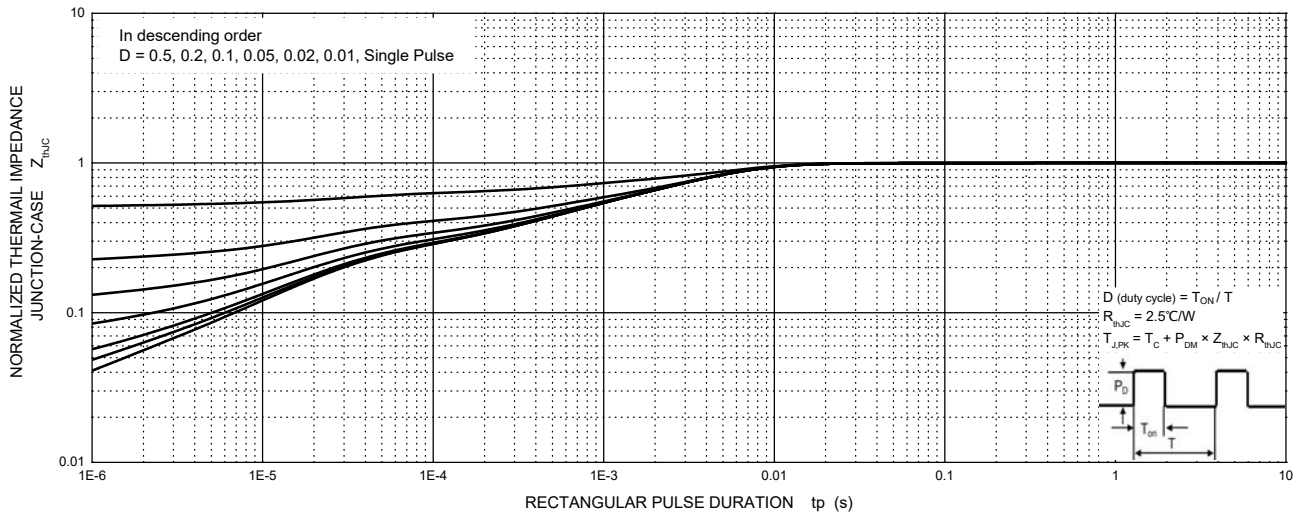
Source-Drain Diode Forward Characteristics



Maximum Safe Operating Area

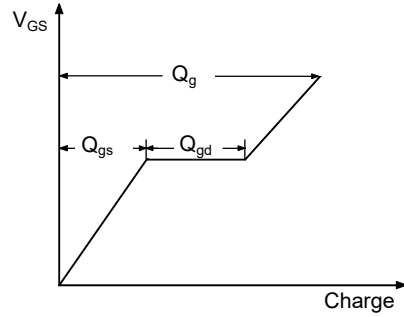


Transient Thermal Impedance, Junction-Case

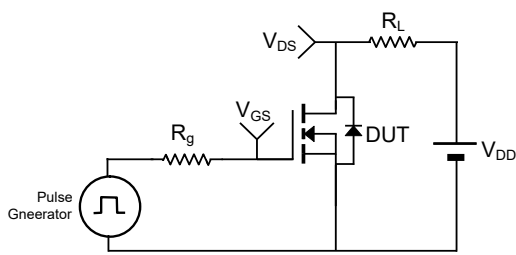


# TEST CIRCUIT AND WAVEFORMS

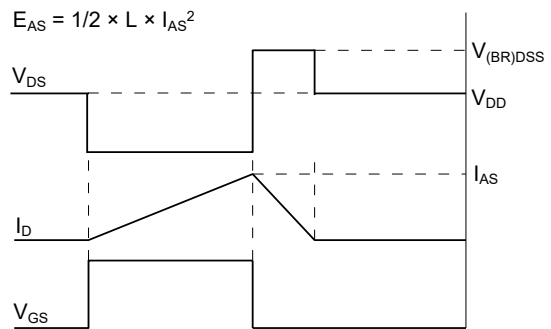
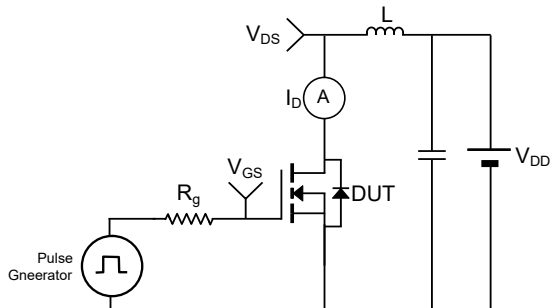
## Gate Charge



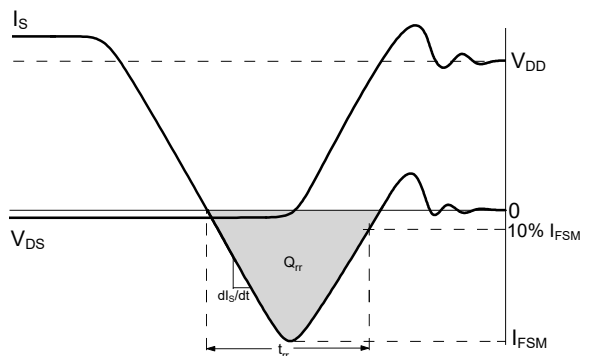
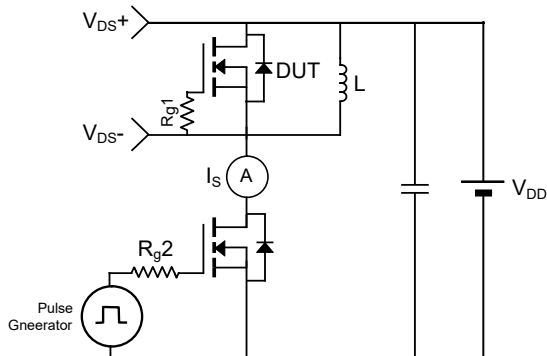
## Resistive Load Switching Time



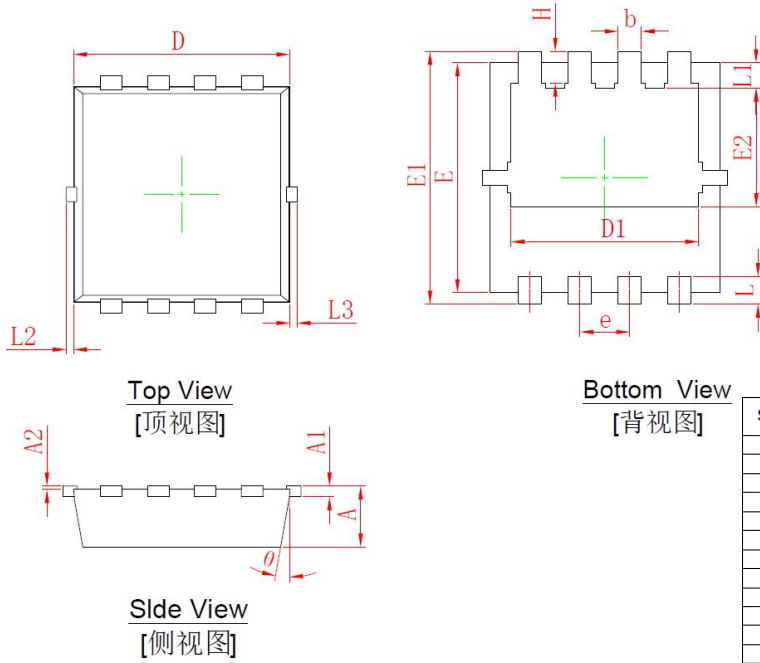
## Un-clamped Inductive Load Switching



## Drain-Source Body Diode Reverse Recovery

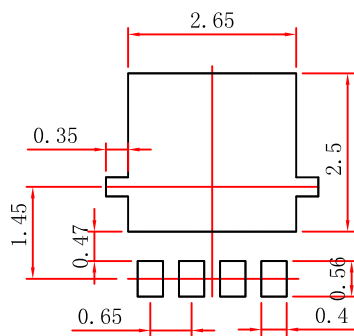


## PDFNWB3.3×3.3-8L-A Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.650	0.850	0.026	0.033
A1	0.203REF.		0.008REF.	
A2	0-0.05		0-0.002	
D	2.900	3.100	0.114	0.122
D1	2.050	2.550	0.081	0.100
E	2.900	3.100	0.114	0.122
E1	3.150	3.450	0.124	0.136
E2	1.450	1.650	0.057	0.065
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0-0.100		0-0.004	
L3	0-0.100		0-0.004	
H	0.315	0.515	0.012	0.020
$\Phi$	9°	13°	9°	13°

## PDFNWB3.3x3.3-8L Suggested Pad Layout



Note:

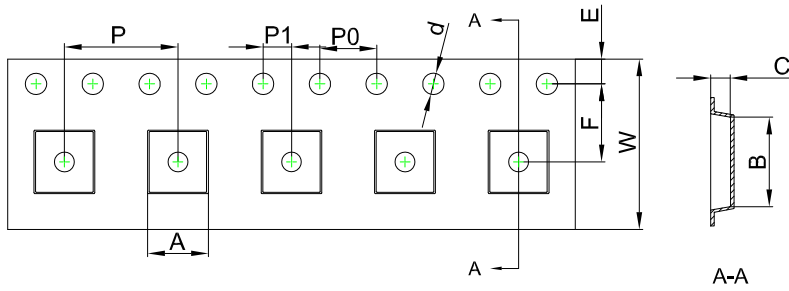
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

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# PDFNWB3.3×3.3-8L Tape and Reel

## PDFNWB3.3×3.3-8L Embossed Carrier Tape



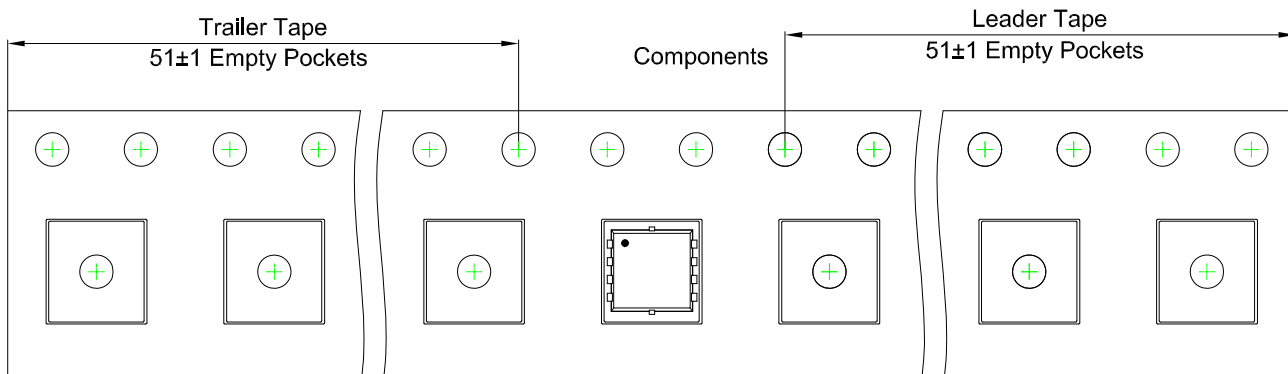
### Packaging Description:

**PDFNWB3.3×3.3-8L** parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

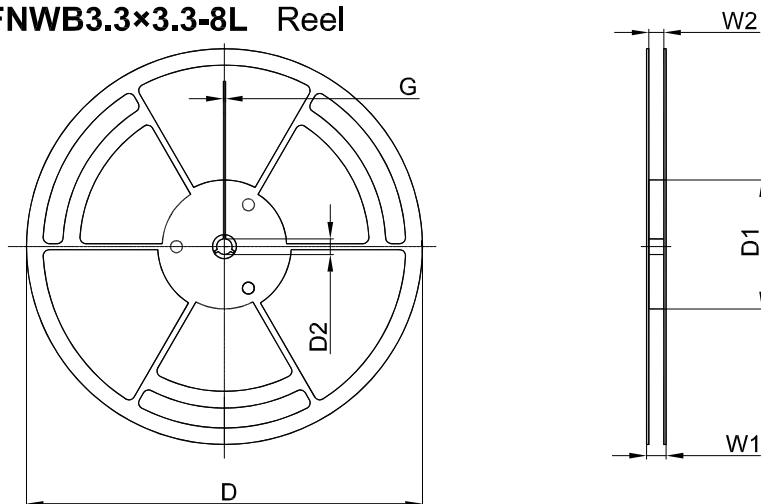
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB3.3×3.3-8L	3.55	3.55	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

## PDFNWB3.3×3.3-8L Tape Leader and Trailer



## PDFNWB3.3×3.3-8L Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	W1	W2
13" Dia	φ330.00	100.00	13.00	1.90	17.60	12.40

Reel	Reel Size	Box	Box Size (mm)	Carton	Carton Size (mm)
5,000 pcs	13 inch	10,000 pcs	360×360×65	50,000 pcs	378×358×382